

“Y” / Descriptions

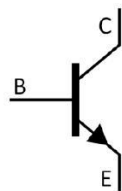
Silicon NPN transistor in a SOT-89 Plastic Package.

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Small flat package, complementary to KTA1664.

High current application.

Դ Զ Դ Զ / Equivalent Circuit



PIN1 Base PIN 2 Collector PIN 3 Emitter

Է. Ի Զ / Marking

h_{FE} Classifications Symbol	O	Y
h_{FE} Range	100 200	160 320
Marking	HPO	HPY

绝对最大额定值(Absolute Maximum Ratings)(Ta=25℃)

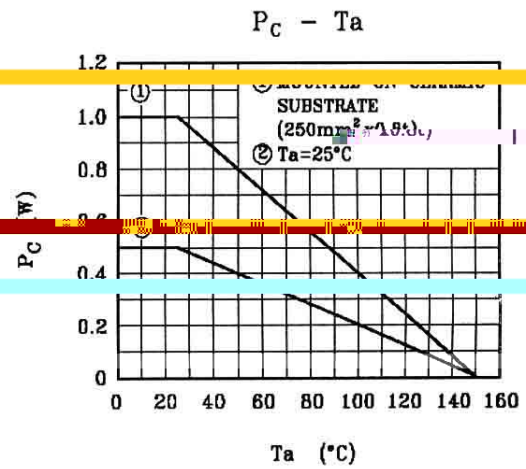
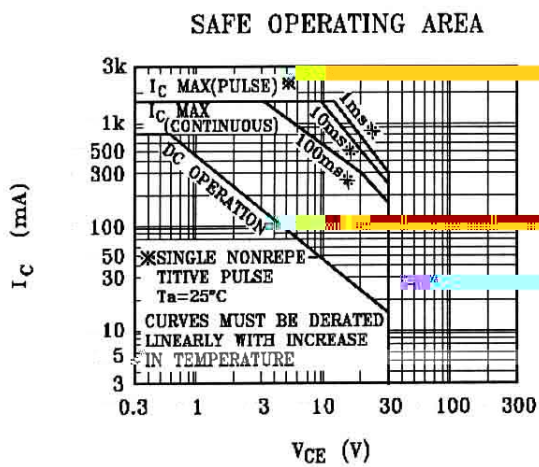
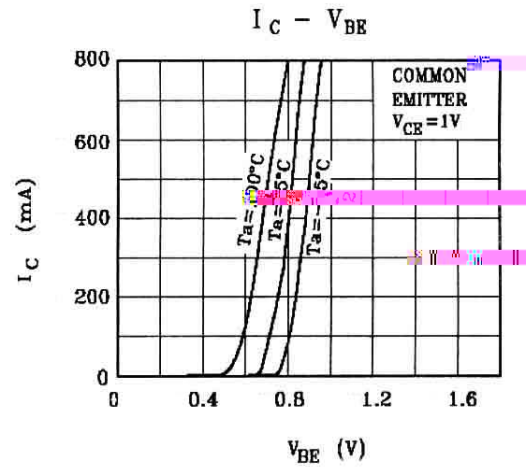
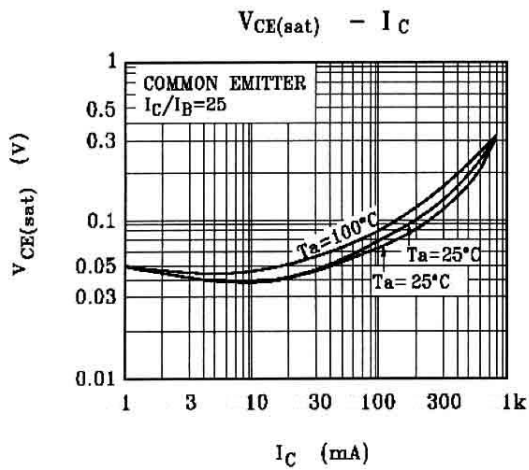
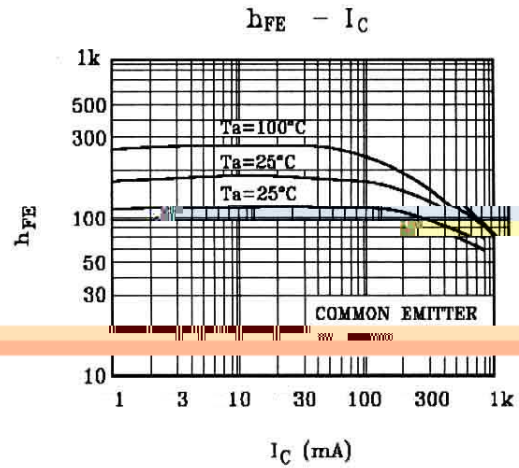
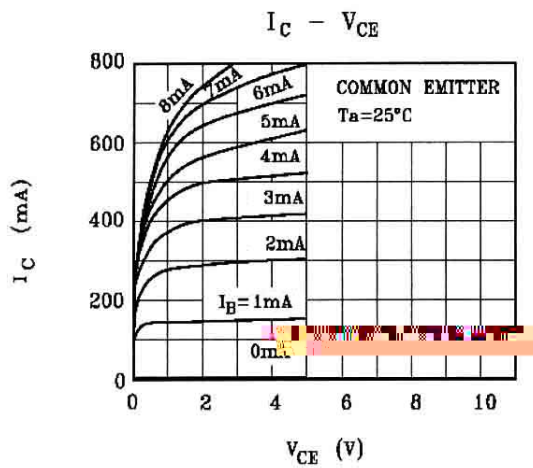
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	35	V
Collector to Emitter Voltage	V_{CEO}	30	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	800	mA
Collector Base – Continuous	I_B	160	mA
Collector Power Dissipation	P_C	500	mW
Collector Power Dissipation*	$*P_C$	1.0	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

* BRKTC4379 mounted on ceramic substrate(250mm²×0.8t).

电 气 特 性 (Electrical Characteristics)(Ta=25℃)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=10mA$ $I_B=0$	30			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=35V$ $I_E=0$			0.1	A
Emitter Base Cut-Off Current	I_{EBO}	$V_{EB}=5.0V$ $I_C=0$			0.1	A
DC Current Gain	$h_{FE(1)}$	$V_{CE}=1.0V$ $I_C=100mA$	100		320	
	$h_{FE(2)}$	$V_{CE}=1.0V$ $I_C=700mA$	35			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=500mA$ $I_B=20mA$			0.5	V
Base to Emitter Voltage	V_{BE}	$V_{CE}=1.0V$ $I_C=10mA$	0.5		0.8	V
Transition Frequency	f_T	$V_{CE}=5.0V$ $I_C=10mA$		120		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V$ $I_E=0$ $f=1.0MHz$		13		pF

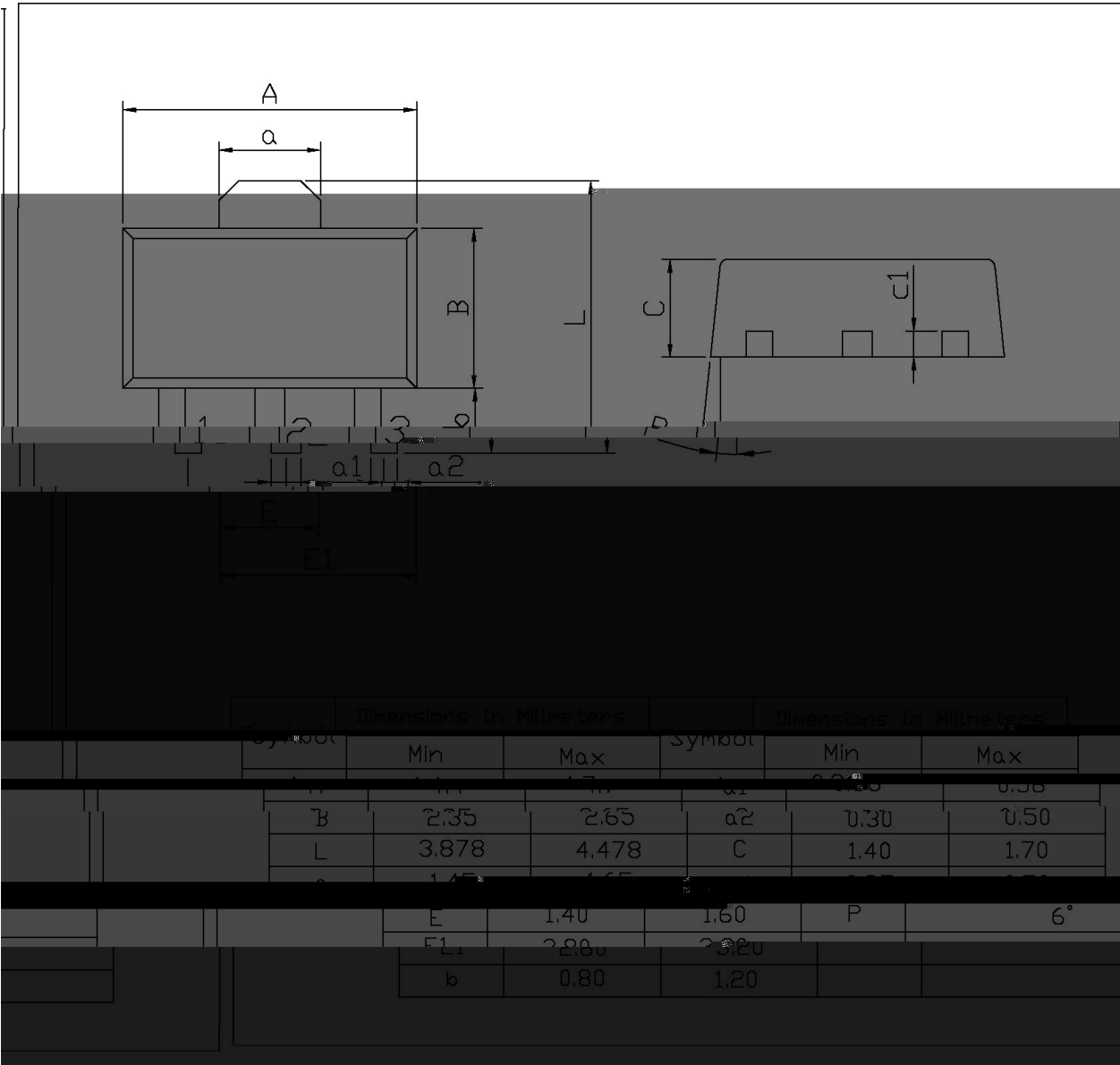
Electrical Characteristic Curve



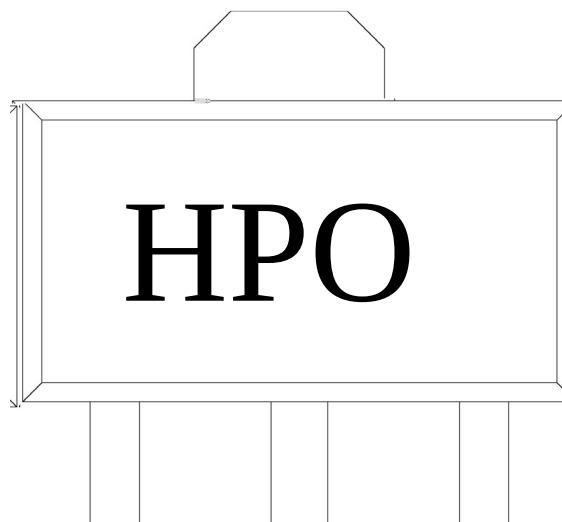
⌘ È Ò Ì ð / Package Dimensions

SOT-89

单位: mm



1. 符号 / Marking Instructions



H
P
O h_{FE}

Note:

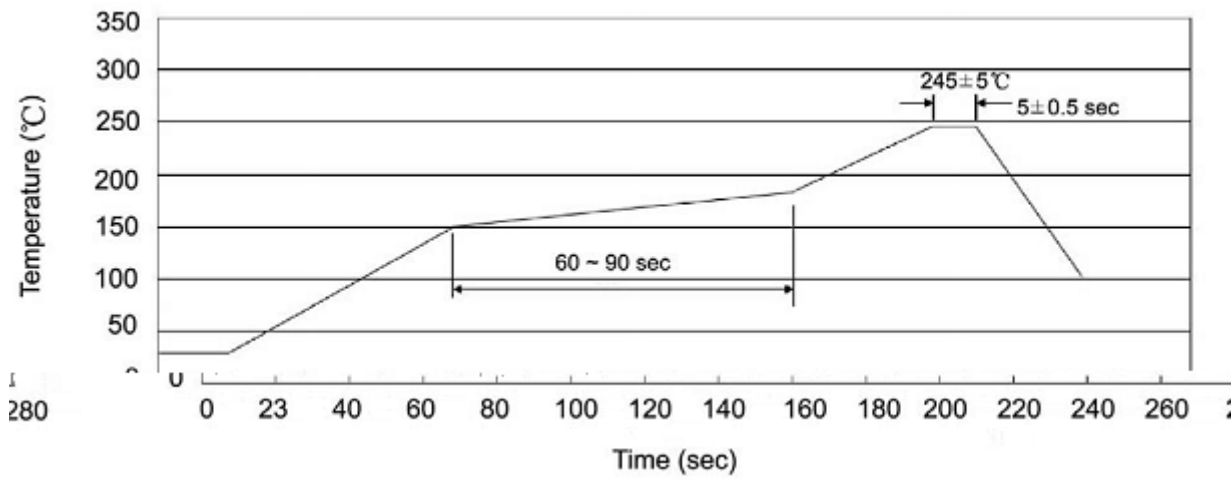
H: Company Code.

P: Product Type.

O h_{FE} Classifications Symbol

** : Lot No. Code, code change with Lot No.

Whp shudwxuh Suriloh i ru LU Uhior z Vroghulqj+Se0luhh,



Note:

- | | | | | | |
|---|-----|-----|----|----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245 | 5 | 5 | 0.5sec; | 2.Peak Temp.:245 5 , Duration:5 0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

Resistance to Soldering Heat Test Conditions

260 5 10 1 sec. Temp.:260±5 Time:10±1 sec

Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱

Notices